Paper / Subject Code: 40624 / Power Electronic Devices & Circuits

1T00834 - S.E.(Electrical Engineering)(SEM-IV)(Choice Base Credit Grading System)(R- 2020-21)(C Scheme) /

40624 - Power Electronic Devices & Circuits DATE: 16/12/2023 QP CODE: 10038111 Time: 3hrs [Total: 80] Note: 1) Question No. 1 is compulsory 2) Attempt any three questions out of remaining five 3) All Questions carry equal marks 4) Assume suitable data if required and state it clearly Q1 Attempt any **FOUR** a. Explain construction of D-MOSFET b. Draw waveforms of different PWM techniques of inverter [5] [5] c. Compare power MOSFET and IGBT d. What is significance of free-wheeling diode, explain with one example and waveforms. [5] e. What is a bootstrap driver circuit? Why it is needed? [5] Q2. a) Differentiate between natural and forced commutation circuits. Explain any two commutation techniques in detail [10] b) Explain single phase full converter with circuit diagram and draw appropriate [10] waveforms. Q3.a) Draw and explain 3-phase bridge inverter for 120 degree conduction mode. [10] b) Explain Turn-ON and Turn-OFF characteristics of SCR with appropriate waveforms. [10] Q4. a) Draw and explain Single phase Dual- Converter [10] b) Write different Turn-ON techniques for SCR [10] Q5.a) Draw and explain Buck regulator with waveforms and derive the relation for output voltage. [10] b) What is Two-transistor's analogy of SCRerive relation for anode current using twotransister's analogy. [10] Q6. Write short notes on (any two) [20] a) Write short notes on Silicon Carbide (SiC) and GaN devices b) Explain SOA of MOSFET with appropriate diagrams c) Performance parameters of Inverter

38111 Page 1 of 1